

L Number	Hits	Search Text	DB	Time stamp
1	214	"4587189"	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/18 09:44
2	19	"5225307"	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/18 09:44
3	2	"6387727"	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/18 09:45
5	220	"4587189" "5225307" "6387727" "20020164835"	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/18 09:45
4	2	"20020164835"	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/18 09:48
6	25	"5981970"	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/18 09:49
7	244	"20020164835" ("4587189" "5225307" "6387727" "20020164835") "5981970"	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/18 09:49
8	58	("20020164835" ("4587189" "5225307" "6387727" "20020164835") "5981970") and cis	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/18 09:53
9	11	((20020164835" ("4587189" "5225307" "6387727" "20020164835") "5981970") and cis) and electrode	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/18 09:54
10	41	("20020164835" ("4587189" "5225307" "6387727" "20020164835") "5981970") and electrodes	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/18 09:57
11	2	((20020164835" ("4587189" "5225307" "6387727" "20020164835") "5981970") and electrodes) and cis	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/18 09:58
12	0	((20020164835" ("4587189" "5225307" "6387727" "20020164835") "5981970") and electrodes) and isomer	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/18 09:59

13	13	"4587189" and isomer	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/18 09:59
14	0	("4587189" and isomer) and (("20020164835" ("4587189" "5225307" "6387727" "20020164835") "5981970") and electrodes)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/18 10:27
15	40679	TFT	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/18 10:27
16	51412	thin adj film adj transistor\$1	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/18 10:28
17	76309	isomer	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/18 10:28
18	26951	TFT and (thin adj film adj transistor\$1)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/18 10:29
19	81	(thin adj film adj transistor\$1) and isomer	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/18 10:29
20	39	((thin adj film adj transistor\$1) and isomer) and cis	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/18 11:06
21	36958	heterocyclic near group	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/18 10:46
22	76	(thin adj film adj transistor\$1) and (heterocyclic near group)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/18 10:48
23	61	((thin adj film adj transistor\$1) and (heterocyclic near group)) and polymer	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/18 10:48
24	1	((((thin adj film adj transistor\$1) and (heterocyclic near group)) and polymer) and cis	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/18 10:53

25	18478	trans same cis same compound\$1	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/18 10:54
26	598	trans near cis near compound\$1	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/18 10:55
27	0	(thin adj film adj transistor\$1) and (trans near cis near compound\$1)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/18 10:55
28	7	(trans near cis near compound\$1) and semiconductor	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/18 10:55
29	187973	heterocyclic	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/18 11:07
30	12	((thin adj film adj transistor\$1) and isomer) and cis) and heterocyclic	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/18 12:38
31	26	"4937164"	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/18 12:38
32	0	"4937164" and TFT	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/18 12:38
33	0	"4937164" and transistor	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/18 12:39
34	0	"4937164" and electrodes	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/18 12:51
35	3	thionated near perylene	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/18 12:53
36	12157	perylene	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/18 12:53

37	609	perylene and (thin adj film adj transistor\$1)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/18 12:54
38	536	(perylene and (thin adj film adj transistor\$1)) and electrodes	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/18 12:54
39	0	((perylene and (thin adj film adj transistor\$1)) and electrodes) and thionated	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/18 12:55
40	2	((perylene and (thin adj film adj transistor\$1)) and electrodes) and isomer	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/18 13:03
41	32867	polycyclic	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/18 13:04
42	2005	polycyclic and electrodes	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/18 13:04
43	151	(polycyclic and electrodes) and TFT	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/18 13:05
44	208	(polycyclic and electrodes) and (thin adj film adj transistor\$1)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/18 13:05
45	3	((polycyclic and electrodes) and TFT) and isomer	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/18 13:05
46	10	((polycyclic and electrodes) and (thin adj film adj transistor\$1)) and isomer	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/18 13:08
47	3	(((polycyclic and electrodes) and (thin adj film adj transistor\$1)) and isomer) and cis	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/18 13:08